

Description

Glass passivated triacs in a plastic envelope, intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance.

Typical applications include motor control, industrial and domestic lighting, heating and static switching.

Symbol Simplified outline

T2 T1

G

T-2-3

TO-220

	G	723 TO-220		
Pin	Description			
1	Main terminal 1 (T1)			
2	Main terminal 2 (T2)			
3	gate (G)			
TAB	Main terminal			

Applications:

- ◆ Motor control
- ♦ Industrial and domestic lighting
- ♦ Heating
- ♦ Static switching

Features

- ♦ Blocking voltage to 600 V
- ♦ On-state RMS current to 8 A

SYMBOL	PARAMETER	Value	Unit
VDRM	Repetitive peak off-state voltages	600	V
IT (RMS)	RMS on-state current (full sine wave)	8	А
Ітѕм	Non-repetitive peak on-state current (full cycle,Tj initial=25°C)	84	А

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$R_{th(j-c)}$	Junction to case(AC)		-	2.5	-	°C/W
$R_{th(j-a)}$	Junction to ambient		-	60	-	°C/W

BTA08-600B

Triacs

HAOPIN MICROELECTRONICS CO.,LTD.

Limiting values in accordance with the Maximum system(IEC 134)

SYMBOL	PARAMETER	CONDITIONS			MIN	Value	UNIT
V _{DRM}	Repetitive peak off-state Voltages				-	600	V
I _{T(RMS)}	RMS on-state current	T _c =100℃			-	8	Α
	Non repetitive surge	Full cycle F=50H _z t=20m		t=20ms	-	80	Α
I _{TSM}	peak on-state current	Tj initial =25℃	F=60H _z	t=16.7ms	-	84	Α
l²t	I ² t value for fusing	T _p =10ms			-	36	A ² S
dI/dt	Critical rate of rise of on-state current	$I_g=2\times I_{gT}$, $tr\leqslant 100$ ns $F=120H_z$ $Tj=125$ °C		-	50	A/μs	
I _{GM}	Peak gate current	tp=20us Tj=125℃		-	4	А	
I _{DRM}	V _{DRM} =V _{RRM}		Tj=25℃		-	5	μ Α
I _{RRM}	V _{DRM} =V _{RRM}	Tj=125℃		-	1	mA	
$P_{G(AV)}$	Average gate power	Tj=125℃		-	1	W	
T _{stg}	Storage temperature range				-40	150	$^{\circ}$
T _j	Operating junction Temperature range				-40	125	$^{\circ}$

T.=25°C unless otherwise stated

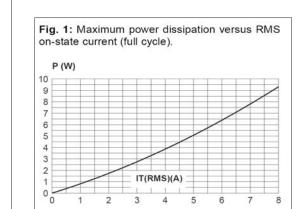
1 ₃ -25 O diffess office wise stated								
SYMBOL	PARAMETER	CONDITIONS			TYP	MAX	UNIT	
Static characteristics								
I _{GT}		V _D =12V; R _L =30 Ω	1-11-111	-	-	50	mA	
			IV			100	mA	
I _L		I _G =1.2 I _{GT}	I-III-IV II	-		50 100	mA mA	
I _H		I _⊤ =500mA		-	-	50	mA	
V _{GT}		V _D =12V; R _L =30 Ω	ALL	-	-	1.3	V	
$V_{\sf GD}$		$V_D = V_{DRM} R_L = 3.3 K \Omega T j = 125 ^{\circ}C$	ALL	0.2	-	-	V	
dV/dt		V _D =67%V _{DRM} gate open;T _J =1	25 ℃	400	-	-	V/μs	
(dV/dt)c	(dI/dt)c=3.5A/ms	T _J =125℃		10	-	-	V/μs	

Dynamic Characteristics

V _{TM}	I _{τм} =11A tp=380 μ s	T _J =25℃	-	-	1.55	V
V _{TO}	Threshold voltage	T _J =125℃	-	-	0.85	V
R _d	Dynamic resistance	T _J =125℃	-	-	50	m Ω



Description



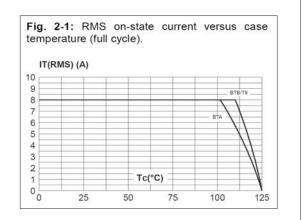
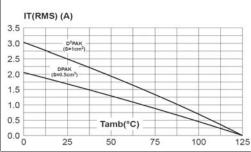
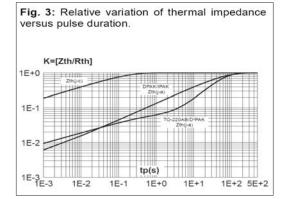
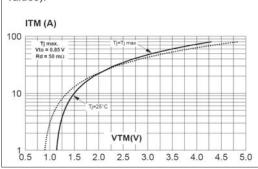


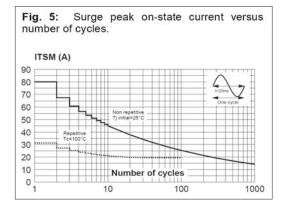
Fig. 2-2: RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35µm),full cycle.





On-state characteristics (maximum Fig. 4: values).







Description

Fig. 6: Non-repetitive surge peak on-state

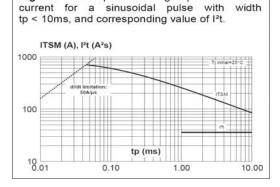


Fig. 7: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values).

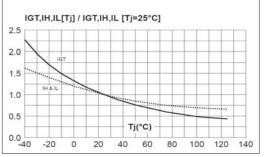


Fig. 8-1: Relative variation of critical rate of decrease of main current versus (dV/dt)c (typical values). Snubberless & Logic Level Types

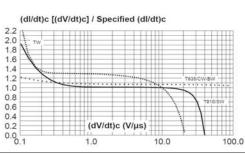


Fig. 8-2: Relative variation of critical rate of decrease of main current versus (dV/dt)c (typical values). Standard Types

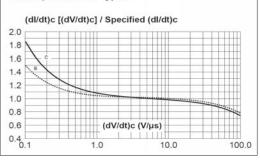


Fig. 9: Relative variation of critical rate of decrease of main current versus junction temperature.

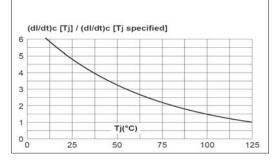
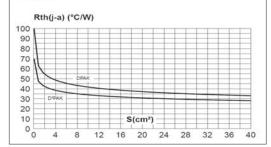


Fig. 10: DPAK and D^2PAK Thermal resistance junction to ambient versus copper surface under tab (printed circuit board FR4, copper thickness: 35 μ m).

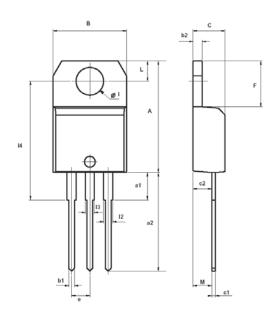




MECHANICAL DATA

Dimensions in mm

Net Mass: 2g TO-220AB



	DIMENSIONS						
REF.	Mi	llimete	ers		Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	15.20		15.90	0.598		0.625	
a1		3.75			0.147		
a2	13.00		14.00	0.511		0.551	
В	10.00		10.40	0.393		0.409	
b1	0.61		0.88	0.024		0.034	
b2	1.23		1.32	0.048		0.051	
С	4.40		4.60	0.173		0.181	
c1	0.49		0.70	0.019		0.027	
c2	2.40		2.72	0.094		0.107	
е	2.40		2.70	0.094		0.106	
F	6.20		6.60	0.244		0.259	
- 1	3.75		3.85	0.147		0.151	
14	15.80	16.40	16.80	0.622	0.646	0.661	
L	2.65		2.95	0.104		0.116	
12	1.14		1.70	0.044		0.066	
13	1.14		1.70	0.044		0.066	
М		2.60			0.102		